Preliminary

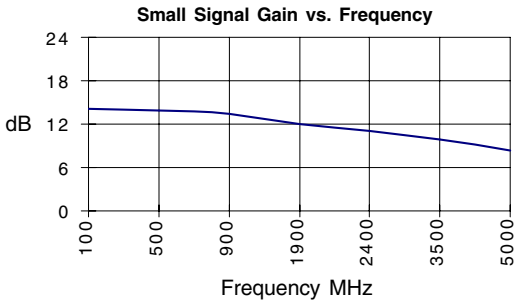
SGA-4286

DC-3500 MHz Silicon Germanium HBT Cascadeable Gain Block

Product Description

Stanford Microdevices' SGA-4286 is a high performance cascadeable 50-ohm amplifier designed for operation at voltages as low as 3.2V. This RFIC uses the latest Silicon Germanium Heterostructure Bipolar Transistor (SiGe HBT) process featuring 1 micron emitters with F_T up to 65 GHz.

This circuit uses a darlington pair topology with resistive feedback for broadband performance as well as stability over its entire temperature range. Internally matched to 50 ohm impedance, the SGA-4286 requires only DC blocking and bypass capacitors for external components.



Product Features

- **DC-3500 MHz Operation**
- **Single Voltage Supply**
- **Low Current Draw: 45mA at 3.2V typ.**
- **High Output Intercept: >+29dBm typ. at 850 MHz**
- **High Power Efficiency: >20%**

Applications

- **Oscillator Amplifiers**
- **IF/ RF Buffer Amplifier**
- **Drivers for CATV Amplifiers**
- **PA for Low Power Applications**

Symbol	Parameters: Test Conditions: Z_0 = 50 Ohms, Id = 45 ma, T = 25°C		Units	Min.	Typ.	Max.
P_{1dB}	Output Power at 1dB Compression	f = 850 MHz f = 1950 MHz	dBm dBm		15.0 12.3	
S_{21}	Small Signal Gain	f = DC - 1000 MHz f = 1000 - 2000 MHz f = 2000 - 3500 MHz	dB dB dB	12.0	13.4 12.0 10.0	
S_{12}	Reverse Isolation	f = DC - 1000 MHz f = 1000 - 2000 MHz f = 2000 - 3500 MHz	dB dB dB		18.6 18.9 18.0	
S_{11}	Input VSWR	f = DC-2400 MHz f = 2400-3500 MHz	-		1.22:1 1.35:1	
S_{22}	Output VSWR	f = DC-2400 MHz f = 2400-3500 MHz	-		1.14:1 1.17:1	
IP_3	Third Order Intercept Point	f = 850 MHz f = 1950 MHz	dBm dBm		29.1 26.5	
NF	Noise Figure	f = 850 MHz f = 1950 MHz	dB dB		3.7 4.2	
T_D	Group Delay	f = 1000 MHz	pS		119.0	
V_D	Device Voltage		V	2.8	3.2	3.6

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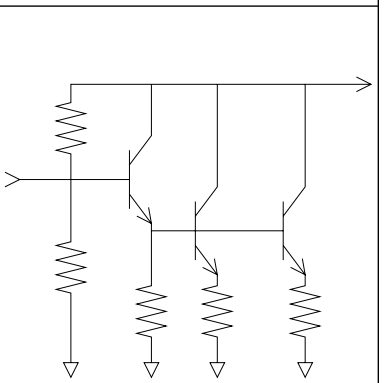
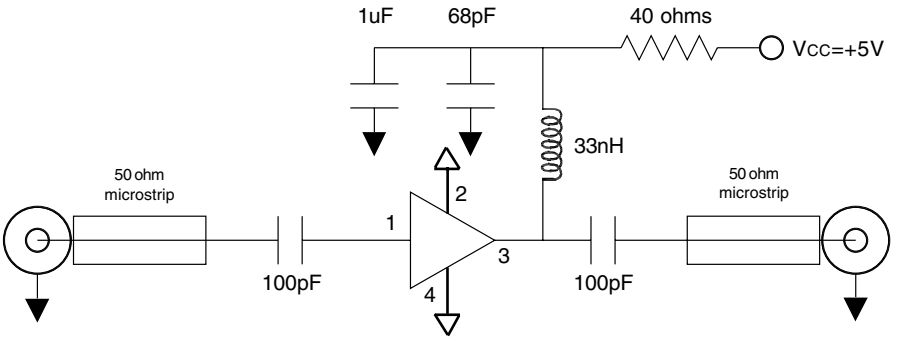
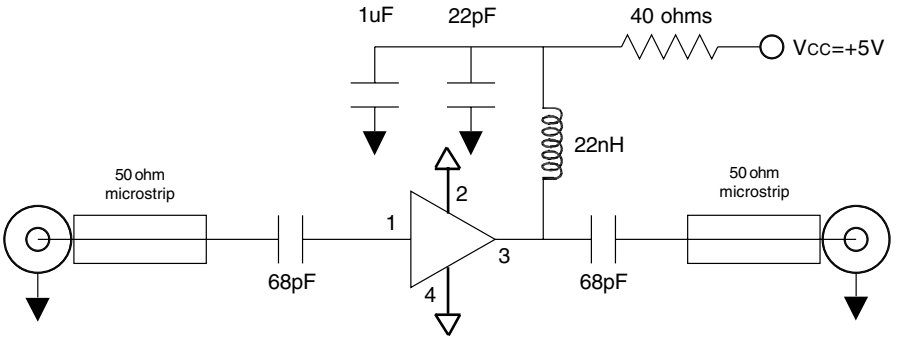
Parameter	Specification				Test Condition
	Min	Typ.	Max.	Unit	
Device Bias					T= 25C
Operating Voltage		3.2		V	
Operating Current		45.0		mA	
500 MHz					T= 25C
Gain		13.9		dB	
Noise Figure		3.6		dB	
Output IP3		29.4		dBm	
Output P1dB		14.7		dBm	
Input Return Loss		23.8		dB	
Isolation		18.2		dB	
850 MHz					T= 25C
Gain		13.4		dB	
Noise Figure		3.7		dB	
Output IP3		29.1		dBm	
Output P1dB		15.0		dBm	
Input Return Loss		20.7		dB	
Isolation		18.6		dB	
1950 MHz					T= 25C
Gain		12.0		dB	
Noise Figure		4.2		dB	
Output IP3		26.5		dBm	
Output P1dB		12.3		dBm	
Input Return Loss		24.7		dB	
Isolation		18.9		dB	
2400 MHz					T= 25C
Gain		11.1		dB	
Noise Figure		4.3		dB	
Output IP3		25.2		dBm	
Output P1dB		11.0		dBm	
Input Return Loss		20.2		dB	
Isolation		19.4		dB	

Pin #	Function	Description	Device Schematic
1	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.	
2	GND	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible.	
3	RF OUT/ BIAS	RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper operation.	
4	GND	Sames as Pin 2	

Application Schematic for +5V Operation at 900 MHz

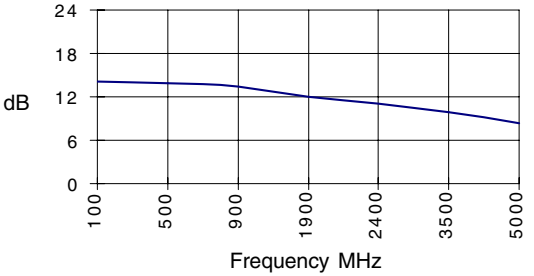


Application Schematic for +5V Operation at 1900 MHz

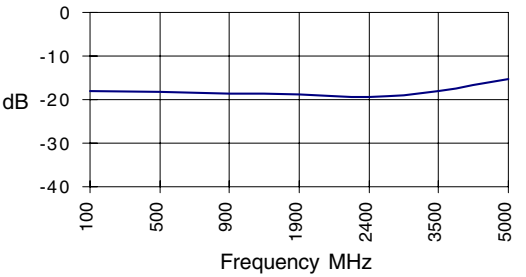


SGA-4286 DC-3500 MHz 3.2V SiGe Amplifier

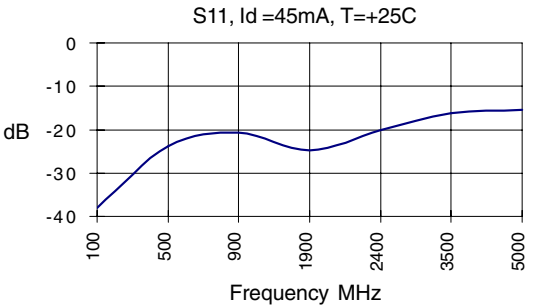
S21, Id =45mA, T=+25C



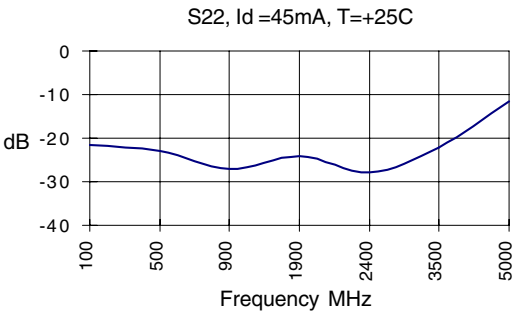
S12, Id =45mA, T=+25C



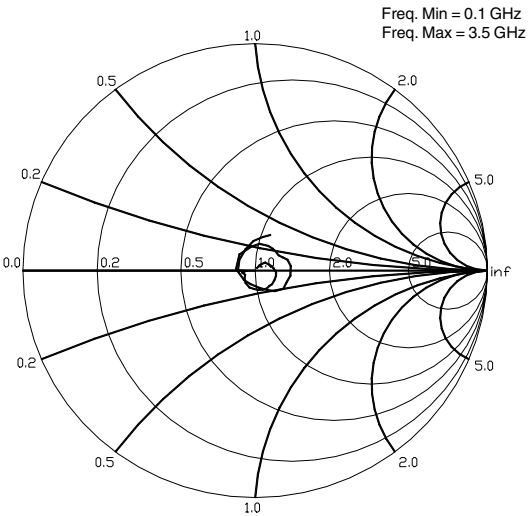
S11, Id =45mA, T=+25C



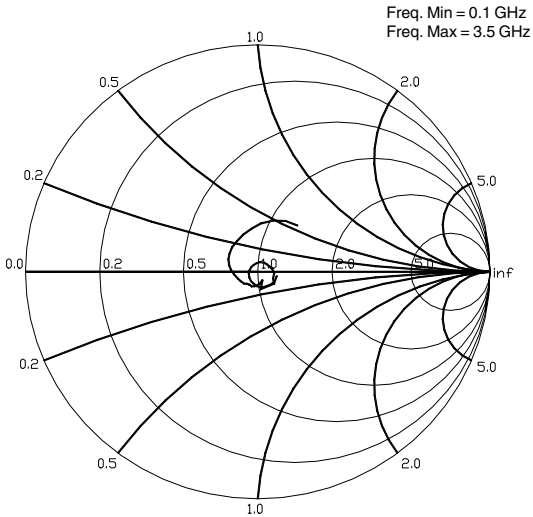
S22, Id =45mA, T=+25C



S11, Id=45mA, Ta= +25C



S22, Id=45mA, Ta= +25C



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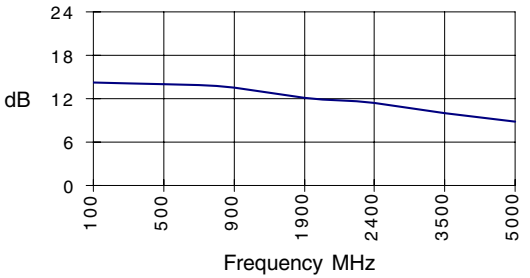
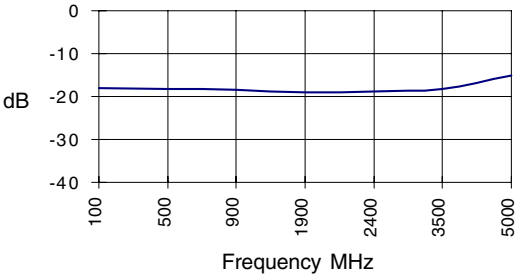
SGA-4286 DC-3500 MHz 3.2V SiGe Amplifier

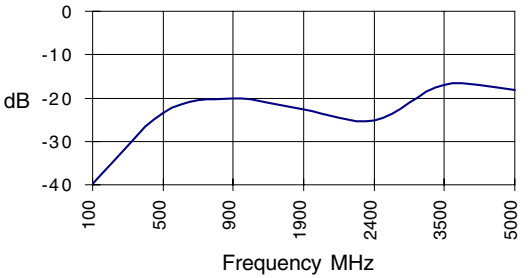
S21, Id =45mA, T=-40C



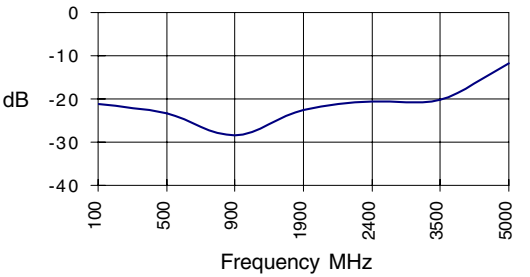
S12, Id =45mA, T=-40C



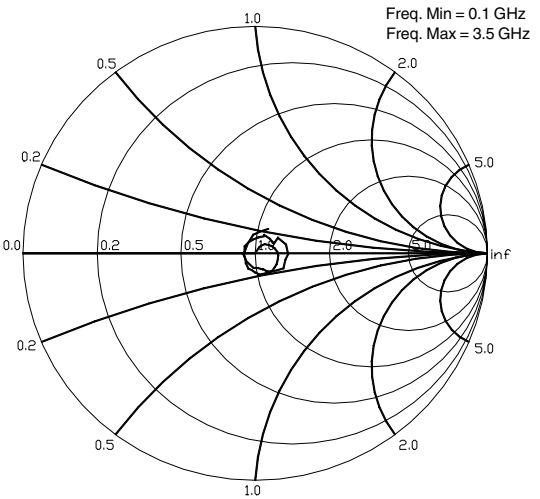
S11, Id =45mA, T=-40C



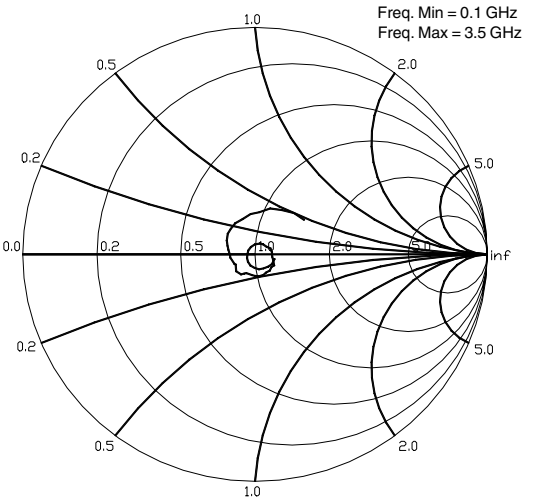
S22, Id =45mA, T=-40C



S11, Id=45mA, Ta= -40C

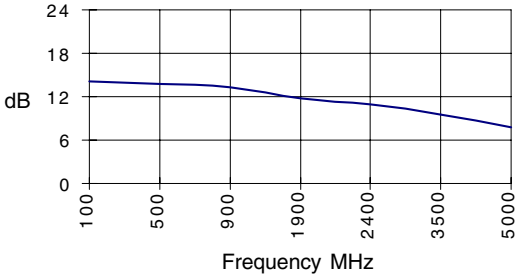


S22, Id=45mA, Ta= -40C

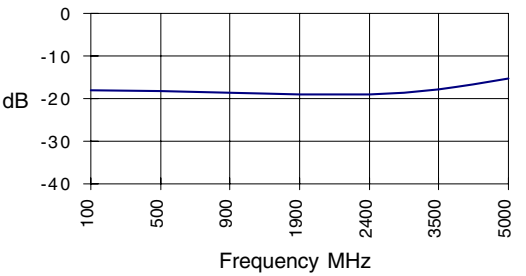


SGA-4286 DC-3500 MHz 3.2V SiGe Amplifier

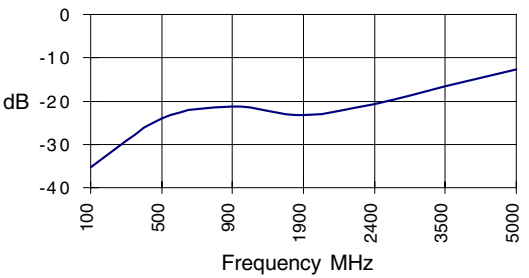
S21, Id =45mA, T=85C



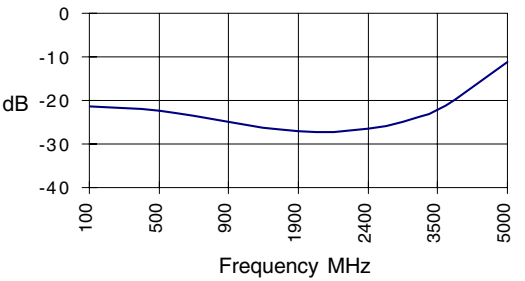
S12, Id =45mA, T=85C



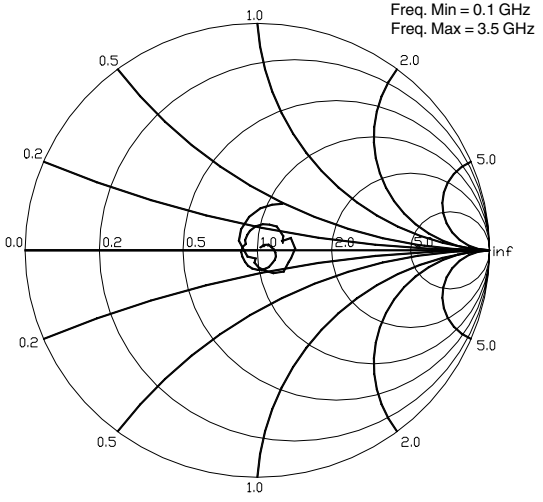
S11, Id =45mA, T=85C



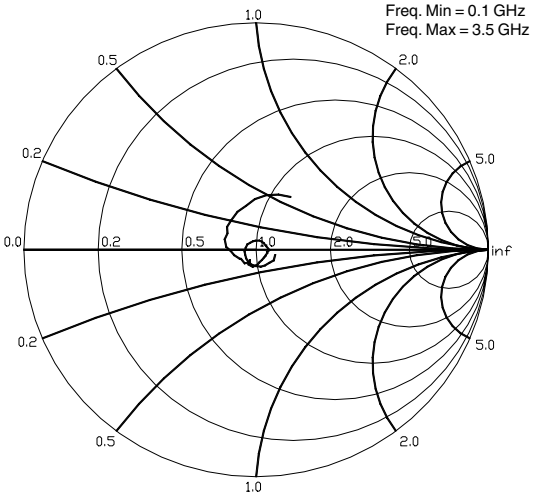
S22, Id =45mA, T=85C



S11, Id=45mA, Ta= 85C



S22, Id=45mA, Ta= 85C



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STANFORD MICRODEVICES

Preliminary

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Absolute Maximum Ratings

Parameter	Value	Unit
Supply Current	90	mA
Operating Temperature	-40 to +85	C
Maximum Input Power	+13	dBm
Storage Temperature Range	-40 to +85	C
Operating Junction Temperature	+150	C

Caution:

Operation of this device above any one of these parameters may cause permanent damage. Appropriate precautions in handling, packaging and testing devices must be observed.

Thermal Resistance (Lead-Junction): 97° C/W

Part Number Ordering Information

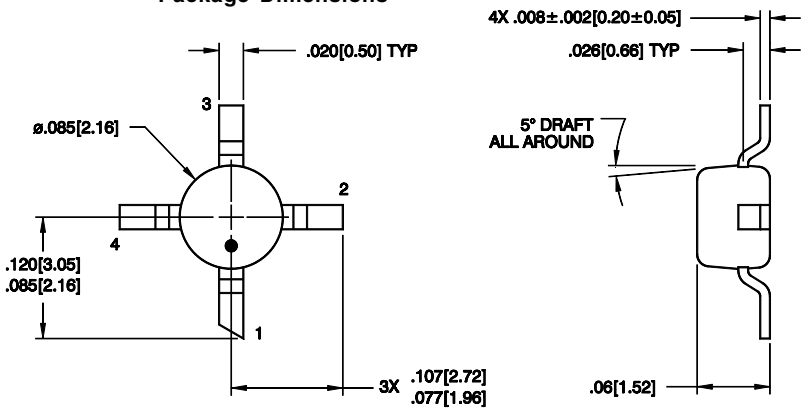
Part Number	Reel Size	Devices/Reel
SGA-4286-TR1	7"	1000
SGA-4286-TR2	13"	3000

Recommended Bias Resistor Values					
Supply Voltage(Vs)	4V	5V	7.5V	9V	12V
Rbias (Ohms)	18	40	96	129	196

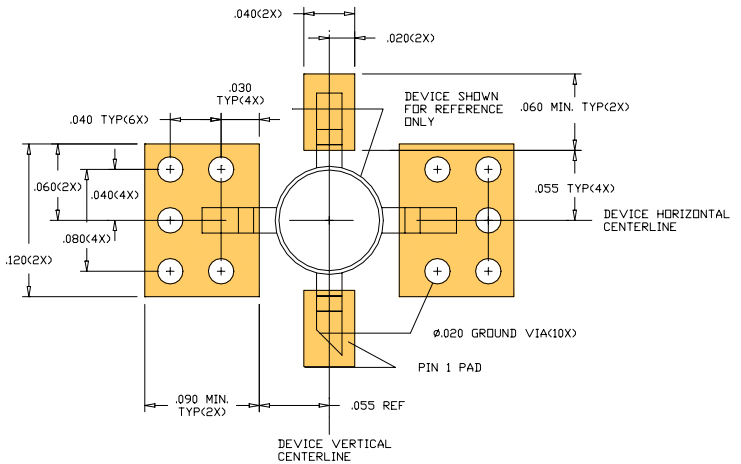
Pin Designation

1	RF in
2	GND
3	RF out and Bias
4	GND

Package Dimensions



PCB Pad Layout



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